



2SB1274/2SD1913

60V/3A Low-Frequency Power Amplifier Applications

Applications

- General power amplifier.

Features

- Wide ASO (Adoption of MBIT process).
- Low saturation voltage.
- High reliability.
- High breakdown voltage.
- Micaless package facilitating mounting.

Specifications

(): 2SB1274

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		(-)60	V
Collector-to-Emitter Voltage	V _{CEO}		(-)60	V
Emitter-to-Base Voltage	V _{EBO}		(-)6	V
Collector Current	I _C		(-)3	A
Collector Current (Pulse)	I _{CP}		(-)8	A
Collector Dissipation	P _C		2	W
		T _c =25°C	20	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics

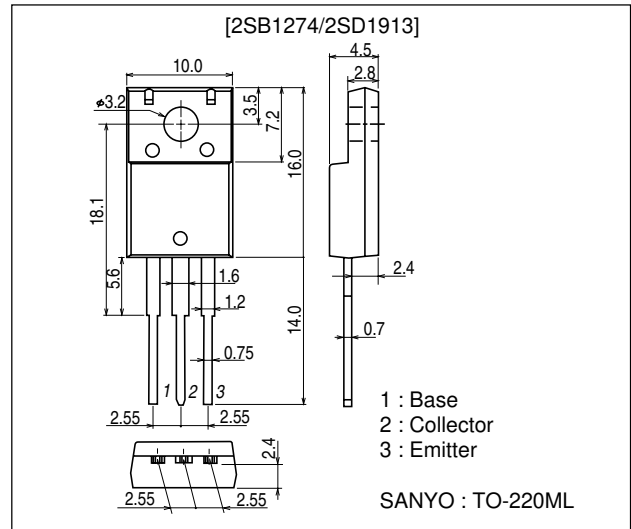
 at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =(-)40V, I _E =0			(-)100	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)100	μA

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Package Dimensions

unit : mm
2041A



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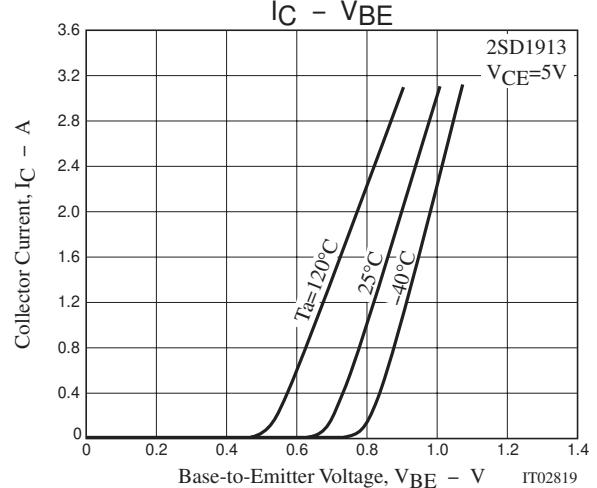
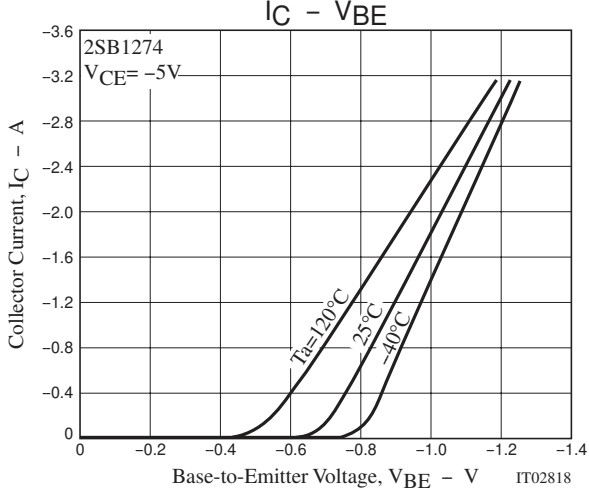
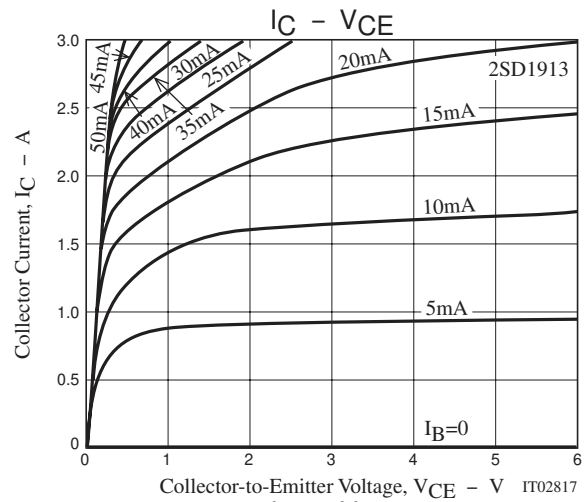
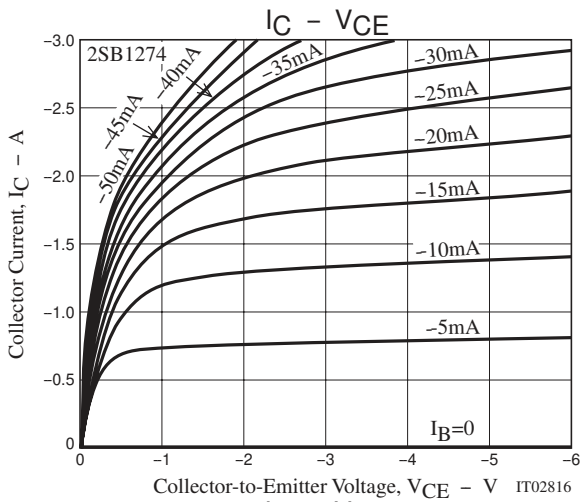
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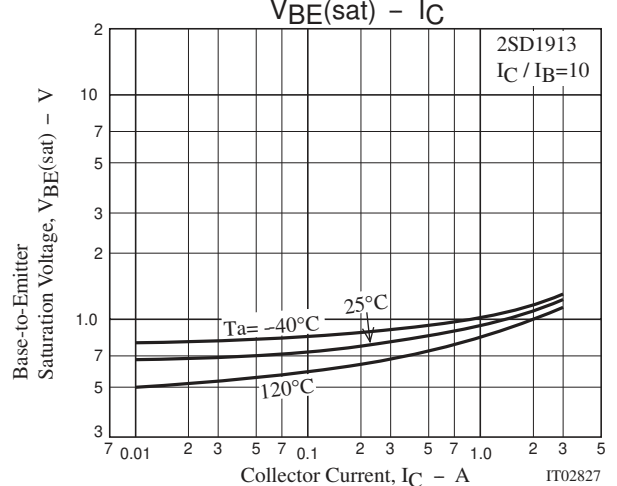
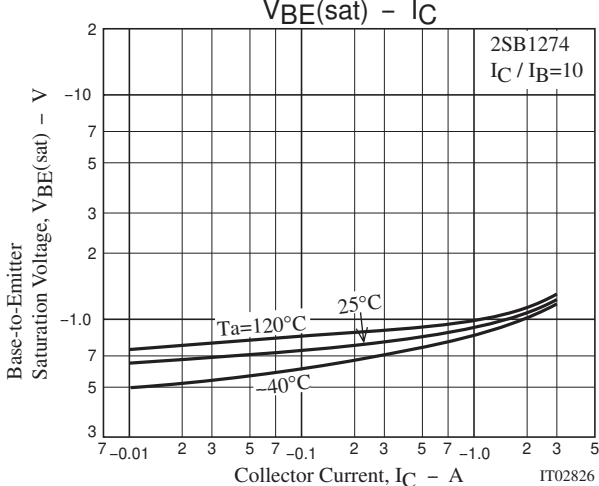
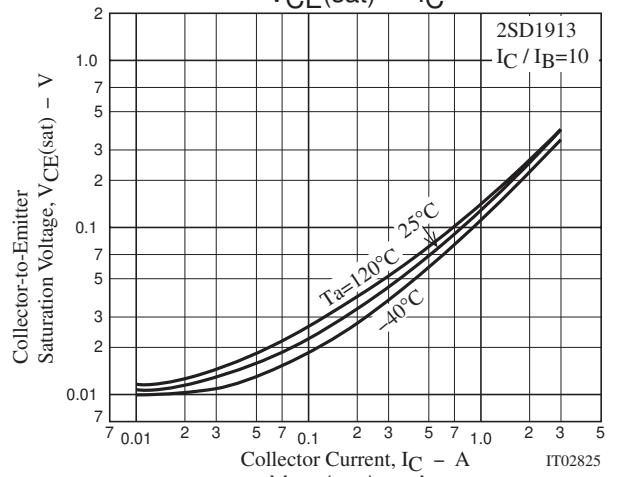
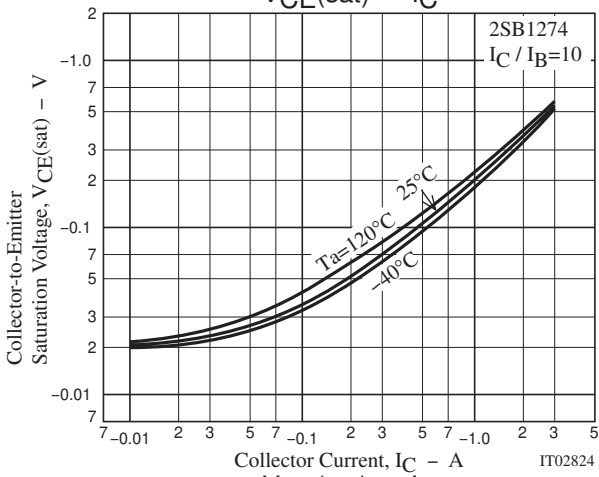
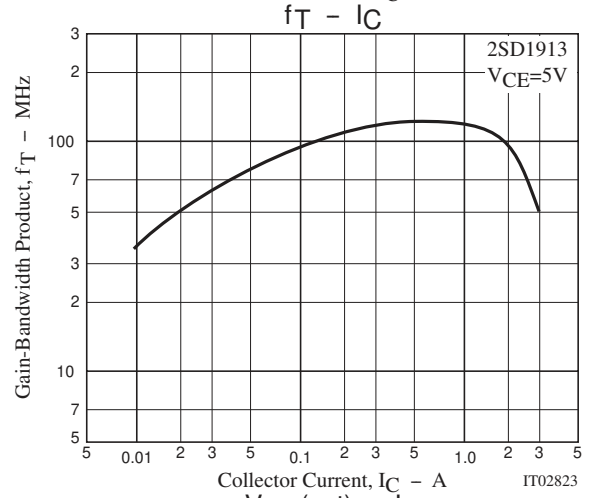
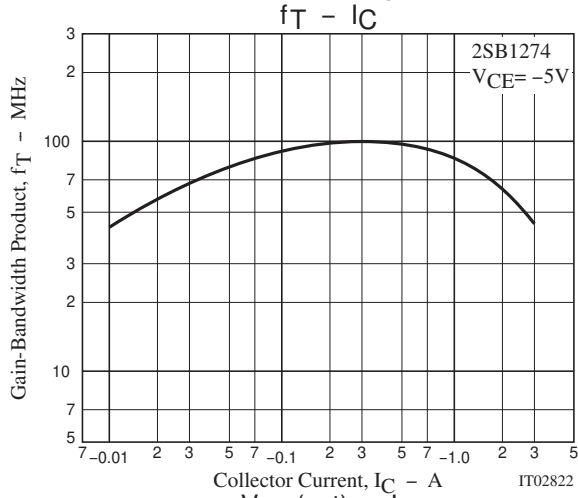
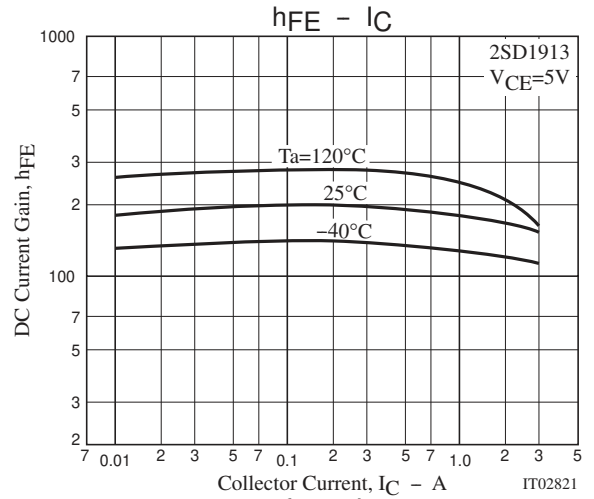
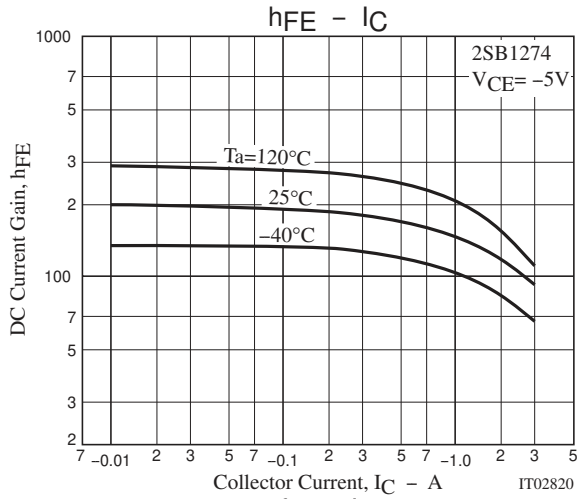
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
DC Current Gain	h_{FE1}	$V_{CE} = (-)5V, I_C = (-)0.5A$	70*		280*	
	h_{FE2}	$V_{CE} = (-)5V, I_C = (-)3A$	20			
Gain-Bandwidth Product	f_T	$V_{CE} = (-)5V, I_C = (-)0.5A$		100		MHz
Output Capacitance	C_{ob}	$V_{CB} = (-)10V, f = 1MHz$		(60)40		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = (-)2A, I_B = (-)0.2A$		(-)0.4	(-)1	V
Base-to-Emitter Voltage	V_{BE}	$V_{CE} = (-)5V, I_C = (-)0.5A$		(-)0.8	(-)1	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)1mA, I_E = 0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 5mA, R_{BE} = \infty$	(-)60			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)1mA, I_C = 0$	(-)6			V

* : The 2SBB1274 / 2SD1913 are classified by 0.5A h_{FE} as follows :

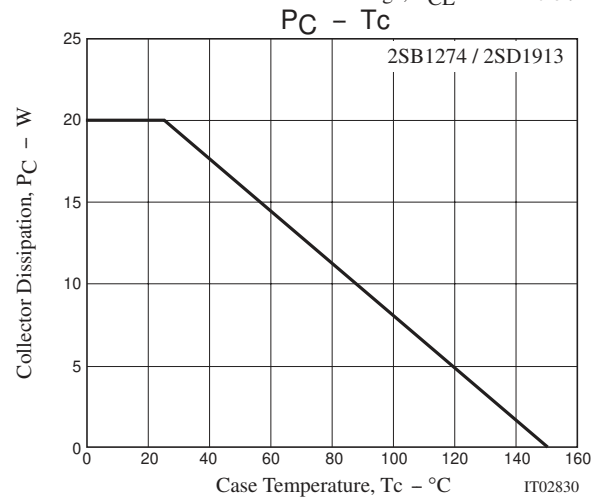
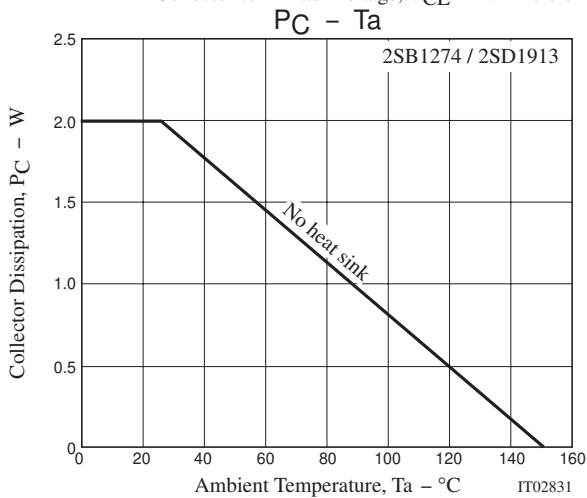
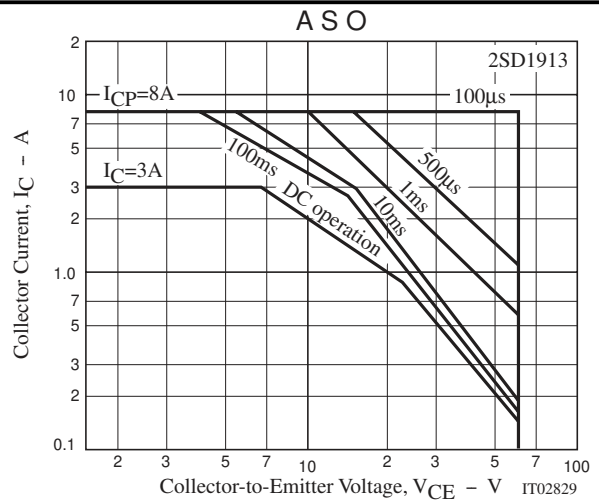
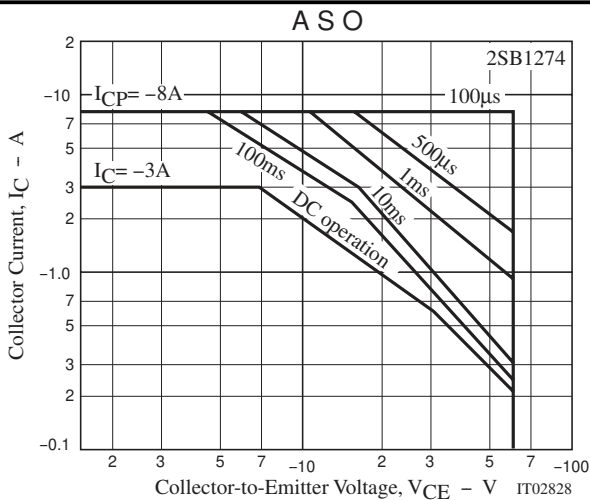
Rank	Q	R	S
h_{FE}	70 to 140	100 to 200	140 to 280



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